Quad 2-Input AND Gate

High-Performance Silicon-Gate CMOS

Features

- Outputs Source/Sink 24 mA
- 'ACT08 Has TTL Compatible Inputs
- These are Pb-Free Devices



Figure 1. Pinout: 14-Lead Packages Conductors (Top View)



ON Semiconductor®



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to $+7.0$	V
VI	DC Input Voltage		$-0.5\leqV_{I}\leqV_{CC}+0.5$	V
Vo	DC Output Voltage	(Note 1)	$-0.5\leqV_O\leqV_{CC}+0.5$	V
I _{IK}	DC Input Diode Current		±20	mA
I _{ОК}	DC Output Diode Current		±50	mA
I _O	DC Output Sink/Source Current		± 50	mA
I _{CC}	DC Supply Current per Output Pin		± 50	mA
I _{GND}	DC Ground Current per Output Pin		±50	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction temperature under Bias		+ 150	°C
θ_{JA}	Thermal Resistance (Note 2)	SOIC TSSOP	125 170	°C/W
P _D	Power Dissipation in Still Air at 85°C	SOIC TSSOP	125 170	mW
MSL	Moisture Sensitivity		Level 1	
F _R	Flammability Rating Oxygen Index:	30% - 35%	UL 94 V-0 @ 0.125 in	
V _{ESD}	ESD Withstand Voltage Human Body Mo Machine Mo Charged Device Mo	del (Note 3) del (Note 4) del (Note 5)	> 2000 > 200 > 1000	V
Latch-Up	Latch-Up Performance Above V _{CC} and Below GND at 85	5°C (Note 6)	± 100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

I_O absolute maximum rating must be observed. 1.

2. The package thermal impedance is calculated in accordance with JESD51-7.

3. Tested to EIA/JESD22-A114-A.

Tested to EIA/JESD22-A115-A. Tested to JESD22-C101-A. 4.

5. 6.

Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Мах	Unit
N	Supply Voltage	′AC	2.0	5.0	6.0	
VCC		′ACT	4.5	5.0	5.5	v
V _{in} , V _{out}	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V _{CC}	V
		V _{CC} @ 3.0 V	-	150	-	ns/V
t _r , t _f	AC Devices except Schmitt Inputs	V _{CC} @ 4.5 V	-	40	-	
		V _{CC} @ 5.5 V	-	25	-	
	Input Rise and Fall Time (Note 2) 'ACT Devices except Schmitt Inputs	V _{CC} @ 4.5 V	-	10	-	
ι _r , ι _f		V _{CC} @ 5.5 V	-	8.0	-	ns/v
TJ	Junction Temperature (PDIP)		-	-	140	°C
T _A	Operating Ambient Temperature Range		-40	25	85	°C
I _{OH}	Output Current – High		-	-	-24	mA
I _{OL}	Output Current – Low		-	-	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. V_{in} from 30% to 70% V_{CC} ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 2. V_{in} from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

DC CHARACTERISTICS

				74	AC	74AC	
			Vcc	T _A =	+25°C	T _A = −40°C to +85°C	
Symbol	Parameter	Conditions	(V)	Тур	Guar	anteed Limits	Unit
V _{IH}	Minimum High Level Input Voltage	V _{OUT} = 0.1 V or V _{CC} - 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V
V _{IL}	Maximum Low Level Input Voltage	V _{OUT} = 0.1 V or V _{CC} - 0.1 V	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V
V _{OH}	Minimum High Level Output Voltage	I _{OUT} = -50 μA	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V
		$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ -12 mA $I_{OH} -24 \text{ mA}$ -24 mA	3.0 4.5 5.5	- - -	2.56 3.86 4.86	2.46 3.76 4.76	v
V _{OL}	Maximum Low Level Output Voltage	$V_{IN} = V_{IL} \text{ or } V_{IH} (\text{Note 3})$ 12 mA I_{OL} 24 mA 24 mA	3.0 4.5 5.5		0.36 0.36 0.36	0.44 0.44 0.44	v
I _{IN}	Maximum Input Leakage Current	V _I = V _{CC} , GND	5.5	-	±0.1	±1.0	μΑ
I _{OLD}	Minimum Dynamic (Note 4)	V _{OLD} = 1.65 V Max	5.5	-	-	75	mA
I _{OHD}	Output Current	V _{OHD} = 3.85 V Min	5.5	-	-	-75	mA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND	5.5	-	4.0	40	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

NOTE: I_{IN} and I_{CC} @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V_{CC}. 3. All outputs loaded; thresholds on input associated with output under test.

4. Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS

			74AC		74/	۹C			
						T _A = -	-40°C		
			T,	∡ = +25° . = 50 מ	C	to +8	35°C 50 pE		
		V _{CC} (V)		L = 30 p		0 <u> </u>	50 pi		Fig.
Symbol	Parameter	(Note5)	Min	Тур	Max	Min	Max	Unit	No.
toru	Propagation Delay	3.3	1.5	7.5	9.5	1.0	10.0	ne	3-5
PLH	Topagation Delay	5.0	1.5	5.5	7.5	1.0	8.5	115	55
t	Propagation Delay	3.3	1.5	7.0	8.5	1.0	9.0	ne	3-5
ΨHL	r lopagation Delay	5.0	1.5	5.5	7.0	1.0	7.5	115	5.2

5. Voltage Range 3.3 V is 3.3 V \pm 0.3 V.

Voltage Range 5.0 V is 5.0 V ± 0.5 V.

DC CHARACTERISTICS

					74 <i>F</i>	СТ	74ACT	
				Vac	т _А = -	+25°C	T _A = −40°C to +85°C	
Symbol	Parameter	Conditio	ons	(V)	Тур	Guar	anteed Limits	Unit
V _{IH}	Minimum High Level	V _{OUT} = 0.1 V		4.5	1.5	2.0	2.0	V
Input Voltage	or V _{CC} – 0.1 V		5.5	1.5	2.0	2.0	V	
V _{IL}	Maximum Low Level	V _{OUT} = 0.1 V		4.5	1.5	0.8	0.8	V
	Input Voltage	or V _{CC} – 0.1 V		5.5	1.5	0.8	0.8	V
V _{OH}	Minimum High Level	I _{OUT} = -50 μA		4.5	4.49	4.4	4.4	V
Output Voltage				5.5	5.49	5.4	5.4	V
		$V_{IN} = V_{IL} \text{ or } V_{IH} (N)$	ote 6)					V
			−24 mA	4.5	-	3.86	3.76	
			−24 mA	5.5	-	4.86	4.76	
V _{OL}	Maximum Low Level	I _{OUT} = 50 μA		4.5	0.001	0.1	0.1	V
	Output Voltage			5.5	0.001	0.1	0.1	v
		$V_{IN} = V_{IL} \text{ or } V_{IH} (N)$	ote 6)					V
			24 mA	4.5	-	0.36	0.44	
			24 mA	5.5	-	0.36	0.44	
I _{IN}	Maximum Input Leakage Current	V _I = V _{CC} , GND		5.5	-	±0.1	±1.0	μΑ
ΔI_{CCT}	Additional Max. I _{CC} /Input	$V_{I} = V_{CC} - 2.1 V$		5.5	0.6	I	1.5	mA
I _{OLD}	Minimum Dynamic (Note 7)	V _{OLD} = 1.65 V Ma	x	5.5	-	-	75	mA
I _{OHD}	Output Current	V _{OHD} = 3.85 V Mir	1	5.5	-	-	-75	mA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND		5.5	-	4.0	40	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
6. All outputs loaded; thresholds on input associated with output under test.
7. Maximum test duration 2.0 ms, one output loaded at a time.

AC CHARACTERISTICS

				74ACT		74A	СТ		
			Ŧ		0	T _A = -	-40°C		
				₁ = +25° · = 50 n	F	to + c $C_1 = t$	50 nF		
		V _{CC} (V)				9L .			Fig.
Symbol	Parameter	(Note 8)	Min	Тур	Мах	Min	Мах	Unit	No.
t _{PLH}	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3–5
t _{PHL}	Propagation Delay	5.0	1.0	-	9.0	1.0	10.0	ns	3-5

8. Voltage Range 5.0 V is 5.0 V ± 0.5 V.

CAPACITANCE

Symbol	Parameter	Test Conditions	Value Typ	Unit
C _{IN}	Input Capacitance	$V_{CC} = 5.0 V$	4.5	pF
C _{PD}	Power Dissipation Capacitance	V _{CC} = 5.0 V	20	pF

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74AC08DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC74AC08DR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74AC08DTR2G	TSSOP-14 (Pb-Free)	2500 / Tape & Reel
MC74ACT08DG	SOIC-14 (Pb-Free)	55 Units / Rail
MC74ACT08DR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel
MC74ACT08DTR2G	TSSOP-14 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS





DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS





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